2SC2236

TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)



Audio Power Amplifier Applications

查询2SC2236\_06供应商

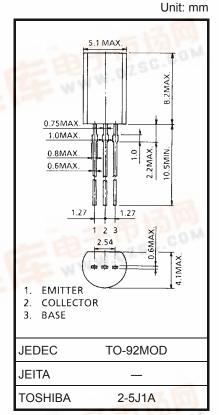
TOSHIBA

• Complementary to 2SA966 and 3-watt output applications.

#### Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V <sub>CBO</sub>	30	V
Collector-emitter voltage	V <sub>CEO</sub>	30	V
Emitter-base voltage	V <sub>EBO</sub>	5	V
Collector current	Ι <sub>C</sub>	1.5	А
Base current	Ι <sub>Β</sub>	0.15	А
Collector power dissipation	PC	900	mW
Junction temperature	Tj	150	°C
Storage temperature range	T <sub>stg</sub>	-55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.



Weight: 0.36 g (typ.)

Please design the appropriate reliability upon reviewing the

Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

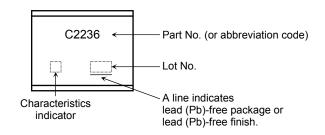
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### Electrical Characteristics (Ta = 25°C)

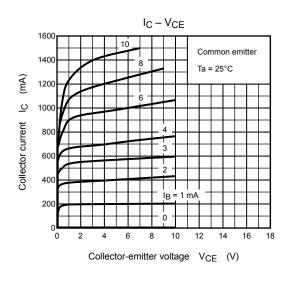
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = 30 V, I <sub>E</sub> = 0	_	_	100	nA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = 5 V, I <sub>C</sub> = 0	_	_	100	nA
Collector-emitter breakdown voltage	V (BR) CEO	I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0	30	_	_	V
Emitter-base breakdown voltage	V (BR) EBO	I <sub>E</sub> = 1 mA, I <sub>C</sub> = 0	5	_	_	V
DC current gain	h <sub>FE</sub> (Note)	V <sub>CE</sub> = 2 V, I <sub>C</sub> = 500 mA	100	_	320	
Collector-emitter saturation voltage	V <sub>CE (sat)</sub>	I <sub>C</sub> = 1.5 A, I <sub>B</sub> = 0.03 A	_	_	2.0	V
Base-emitter voltage	V <sub>BE</sub>	V <sub>CE</sub> = 2 V, I <sub>C</sub> = 500 mA	_	_	1.0	V
Transition frequency	fT	V <sub>CE</sub> = 2 V, I <sub>C</sub> = 500 mA	_	120	_	MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz	_	_	30	pF

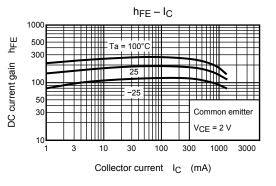
Note: hFE classification O: 100 to 200, Y: 160 to 320

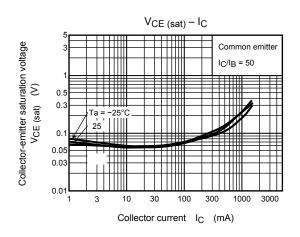
### Marking

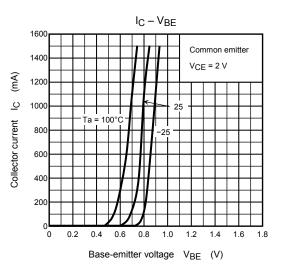


## **TOSHIBA**

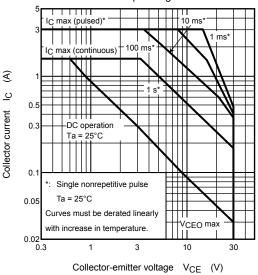


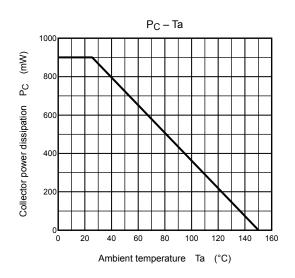






Safe Operating Area





# TOSHIBA

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Handbook" etc.

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